

DESCRIPTION

The MOC3051 and MOC3052 are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a light activated silicon bilateral switch performing the functions of a triac.

These photocouplers provide random phase control of high current triacs or thyristors. The MOC3051 and MOC3052 feature greatly enhanced static dv/dt capability to ensure stable switching performance of inductive loads.

These devices are mounted in a standard 6 pin dual-in-line package.

1 6 5 5 3 4



- Anode
- 2 Cathode
- 3 NC
- 4 Main Terminal
- 5 Substrate (Do not Connect)
- 6 Main Terminal

FEATURES

- High Repetitive Peak Off-state Voltage V_{DRM}: minimum 600V
- High Critical Rate of Rise of Off-state Voltage dv/dt: minimum 1000V/µs)
- High Isolation Voltage between Input and Output Viso: 5000Vrms
- Lead Free and RoHS Compliant
- UL File No. E91231
- VDE File No. 40028086

APPLICATIONS

- Solenoid / Valve Controls
- Lamp Ballasts
- Static AC Power Switch
- Interfacing Microprocessors to 115 and 240Vac Peripherals
- Solid State Relays
- Incandescent Lamp Dimmers
- Temperature Controls
- Motor Controls

ORDER INFORMATION

- Add Suffix "X" for VDE Approval
- Add G after PN for 10mm lead spacing
- Add SM after PN for Surface Mount
- Add SMT&R after PN for Surface Mount Tape & Reel

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	50mA
Reverse Voltage	6V
Power dissination	100mV

Output

Peak Repetitive Surge Current	1A
(Pulse width = 1ms, 120pps)	
Off State Output Terminal Voltage	600V
Power Dissipation	300mW

Total Package

Isolation Voltage	$5000V_{RMS}$
Total Power Dissipation	330mW
Operating Temperature	-40 to 100 °C
Storage Temperature	-55 to 150 °C
Lead Soldering Temperature (10s)	260°C

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\rm F}$	$I_F = 20 \text{mA}$		1.2	1.5	V
Reverse Current	I_R	$V_R = 6V$		0.05	10	μA

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak Off-state Current Either Direction	${ m I}_{ m DRM}$	$V_{DRM} = 600V$ $I_F = 0mA$ Note 1			100	nA
On-State Voltage Either Direction	V_{TM}	$I_{TM} = 100 \text{mA (peak)}$			3.0	V
Critical Rate of Rise of Off-State Voltage	dv/dt	$I_F = 0mA$	1000			V/µs

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Input Trigger Current	I_{FT}	$V_{TM} = 3V$				mA
Either Direction		Note 2				
		MOC3051			15	
		MOC3052			10	
Holding Current Either Direction	I_{H}			200		μA

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Insulation Voltage	$V_{\rm ISO}$	AC 1 minute, RH 40 to 60%	5000			V_{RMS}
		Note 3				

Note 1: Test Voltage must be applied within static dv/dt rating.

Note 2 : Guaranteed to trigger at an I_F value less than or equal to max I_{FT} , recommended I_F lies between Rated I_{FT} to Absolute Max I_F .

Note 3: Measured with input leads shorted together and output leads shorted together.



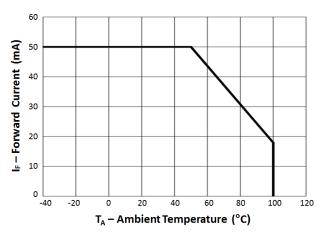


Fig 1 Forward Current vs Ambient Temperature

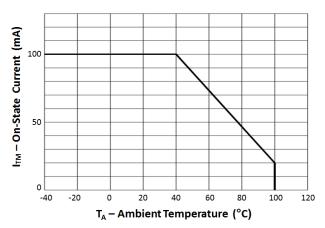


Fig 2 On-State Current vs Ambient Temperature

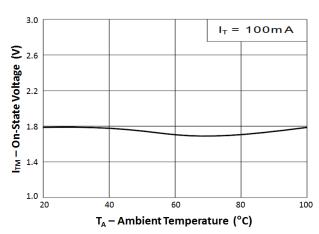


Fig 3 On-State Voltage vs Ambient Temperature

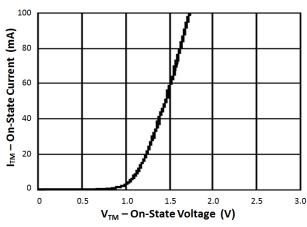


Fig 4 On-State Current vs On-State Voltage

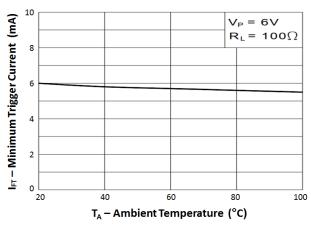


Fig 5 Minimum Trigger Current vs Ambient Temperature

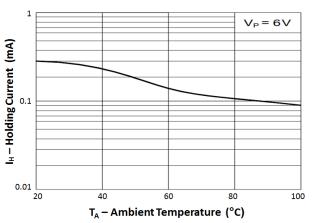


Fig 6 Holding Current vs Ambient Temperature



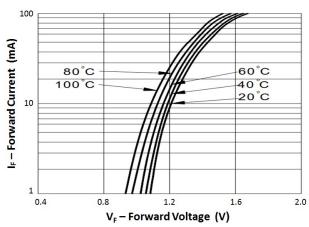


Fig 7 Forward Current vs Forward Voltage

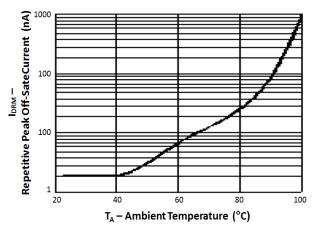


Fig 8 Repetitive Peak Off-State Current vs Ambient Temperature



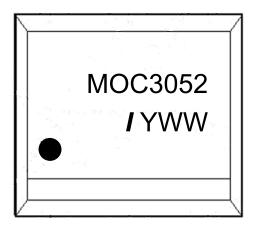
ORDER INFORMATION

	MOC3051 / MOC3052 (UL Approval)				
After PN	PN	Description	Packing quantity		
None	MOC3051, MOC3052	Standard DIP6	65 pcs per tube		
G	MOC3051G, MOC3052G	10mm Lead Spacing	65 pcs per tube		
SM	MOC3051SM, MOC3052SM	Surface Mount	65 pcs per tube		
SMT&R	MOC3051SMT&R, MOC3052SMT&R	Surface Mount Tape & Reel	1000 pcs per reel		

	MOC3051X / MOC3052X (UL Approval and VDE Approvals)					
After PN	PN	Description	Packing quantity			
None	MOC3051X, MOC3052X	Standard DIP6	65 pcs per tube			
G	MOC3051XG, MOC3052XG	10mm Lead Spacing	65 pcs per tube			
SM	MOC3051XSM, MOC3052XSM	Surface Mount	65 pcs per tube			
SMT&R	MOC3051XSMT&R, MOC3052XSMT&R	Surface Mount Tape & Reel	1000 pcs per reel			

DEVICE MARKING

Example: MOC3052



MOC3052 denotes Device Part Number

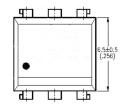
denotes Isocom

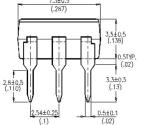
Y denotes 1 digit Year code WW denotes 2 digit Week code

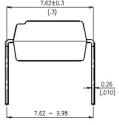


PACKAGE DIMENSIONS in mm (inch)

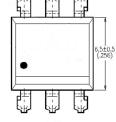


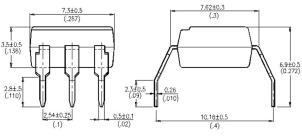




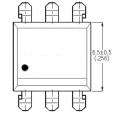


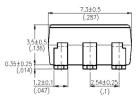
G Form

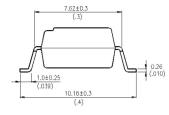




SMD

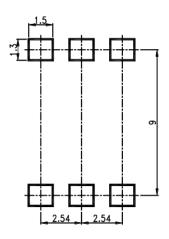




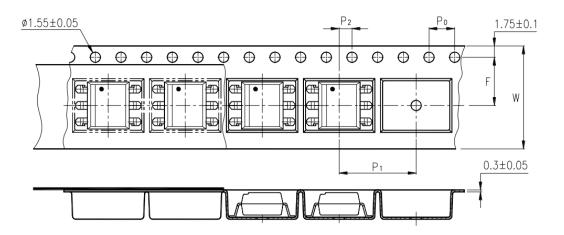




RECOMMENDED PAD LAYOUT FOR SMD (mm)



TAPE AND REEL PACKAGING

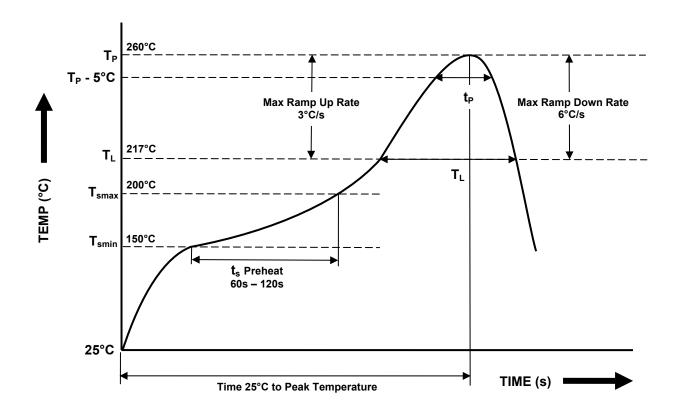


Description	Symbol	Dimension mm (inch)
Tape Width	W	16 ± 0.3 (0.63)
Pitch of Sprocket Holes	P ₀	4 ± 0.1 (0.15)
Distance of Compartment to Sprocket Holes	F	7.5 ± 0.1 (0.295)
Distance of Compartment to Sprocket Holes	P ₂	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P ₁	12 ± 0.1 (0.472)



IR REFLOW SOLDERING TEMPERATURE PROFILE

Note : One Time Reflow Soldering is Recommended. Do Not Immerse Device Body in Solder Paste.



Profile Details	Conditions
$ \begin{array}{l} \textbf{Preheat} \\ \textbf{- Min Temperature } (T_{SMIN}) \\ \textbf{- Max Temperature } (T_{SMAX}) \\ \textbf{- Time } T_{SMIN} \text{ to } T_{SMAX} \left(t_s\right) \end{array} $	150°C 200°C 60s - 120s
$\begin{tabular}{lll} \textbf{Soldering Zone} \\ - & \begin{tabular}{l} - $	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T _{smax} to T _P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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